Form PTO 1449 (Modified) — U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

LIST OF REFERENCES CITED BY APPLICANT

ATTY DOCKET NO.	SERIAL NO.
270767US0PCT	10/532,500
APPLICANT: Marc DELAUNAY, et al.	
FILING DATE: April 25, 2005	GROUP

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
/RK/	AA	6,346,303	02/12/02	SHIH, Han-Chang et al.			
	AB						
	AC						
	AD						
	AE						
	AF						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES	TRANSLATION NO
/RK/	AG	1 129 990	09/05/01	EP		NO
/RK/	AH	98 00777	07/30/99	FR(Equivalent of US 6,319,372)		NO

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☐ Additional References sheet(s) attached

Examiner: /Robert Kunemund/ — Date Considered: 05/11/2007

*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.